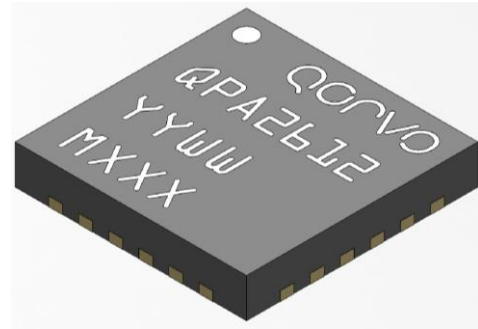


### Product Overview

Qorvo's QPA2612 is a packaged, high performance power amplifier fabricated on Qorvo's production 0.15  $\mu\text{m}$  GaN on SiC process (QGaN15). Covering 8 - 12 GHz, the QPA2612 provides > 12 W of saturated output power and 23 dB of large-signal gain while achieving an impressive 40% power-added efficiency.

Packaged in a small 5 x 5 mm plastic overmold QFN, tight lattice spacing requirements for phased array radar applications is easily supported. RF input and output ports are matched to  $50\Omega$  and are DC grounded. QPA2612 is part of a three-amplifier family and is pin compatible to QPA2610 and QPA2611.

Lead-free and RoHS compliant.

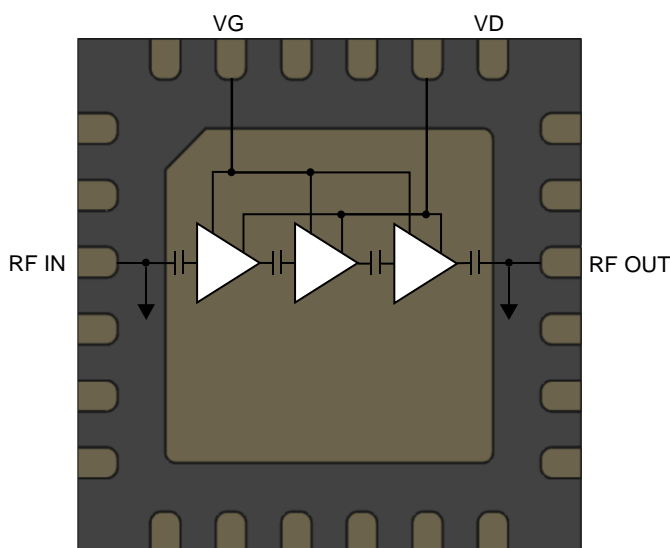


5 mm x 5 mm plastic overmold QFN

### Key Features

- Frequency Range: 8.0 – 12.0 GHz
- Output Power ( $P_{IN} = 18 \text{ dBm}$ ): > 41 dBm
- PAE ( $P_{IN} = 18 \text{ dBm}$ ): > 40 %
- Small Signal Gain: 34 dB
- Input Return Loss: > 16 dB
- Output Return Loss: > 4 dB
- Recommended Bias:  $V_D = 24 \text{ V}$ ,  $I_{DQ} = 250 \text{ mA}$
- Package Size: 5.0 mm x 5.0 mm x 0.85 mm

### Functional Block Diagram



Top View

### Applications

- Radar
- Communications
- Satcom

### Ordering Information

Part No.	Description
QPA2612	12 Watt X-Band Power Amplifier
QPA2612TR7	250 pcs. on 7 inch reel
QPA2612EVB	QPA2612 Evaluation Board

## Absolute Maximum Ratings

Parameter	Rating
Drain Voltage ( $V_D$ )	29.5 V
Gate Voltage Range ( $V_G$ )	-4 to 0 V
Drain Current ( $I_D$ )	1700 mA
Gate Current ( $I_G$ )	See plot pg. 16
Power Dissipation ( $P_{DISS}$ ), CW, 85 °C	26.8 W
Input Power ( $P_{IN}$ ), CW, 50 $\Omega$ , 85 °C	21 dBm
Input Power ( $P_{IN}$ ), CW, VSWR 4:1, $V_D = 24$ V, 85 °C	21 dBm
Mounting Temperature (30 seconds max.)	260 °C
Storage Temperature	-55 to 150 °C

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability.

## Recommended Operating Conditions

Parameter	Typ
Drain Voltage ( $V_D$ )	24 V
Drain Current ( $I_{DQ}$ )	250 mA
Drain Current Under RF Drive ( $I_{D\_DRIVE}$ )	See plots pg. 4
Gate Voltage Range ( $V_G$ )	-2.8 to -2.0 V
Gate Current Under RF Drive ( $I_{G\_DRIVE}$ )	See plots pg. 4

Electrical specifications are measured at specified test conditions. Specifications are not guaranteed over all recommended operating conditions.

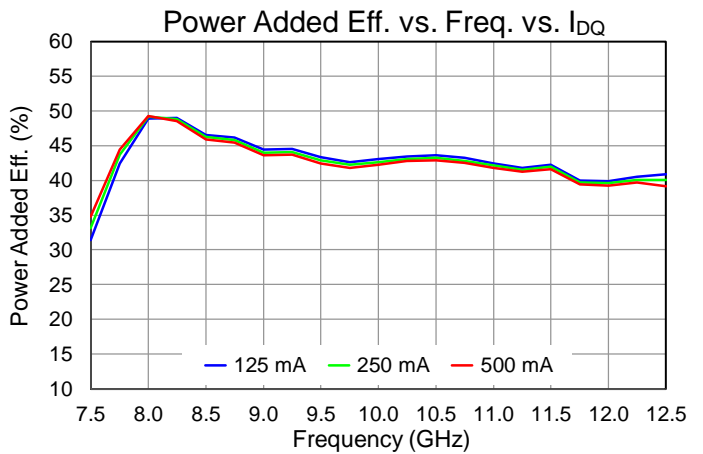
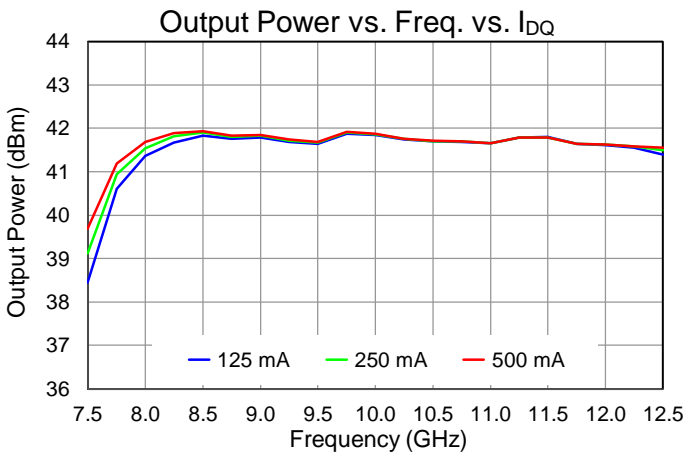
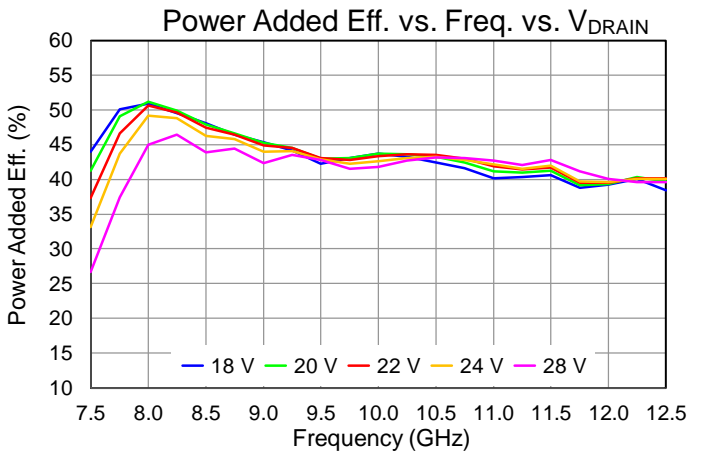
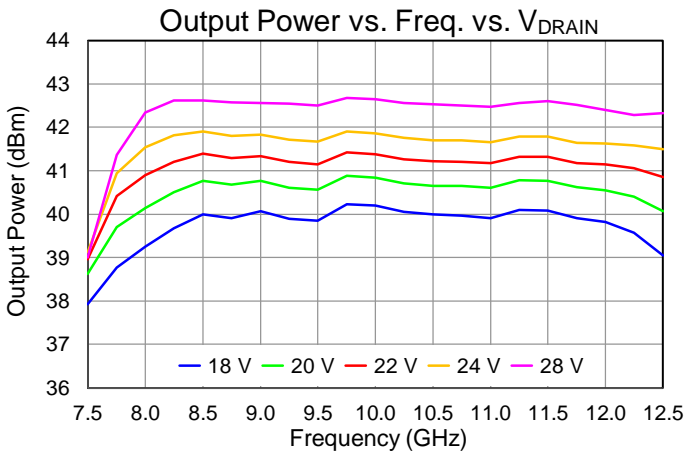
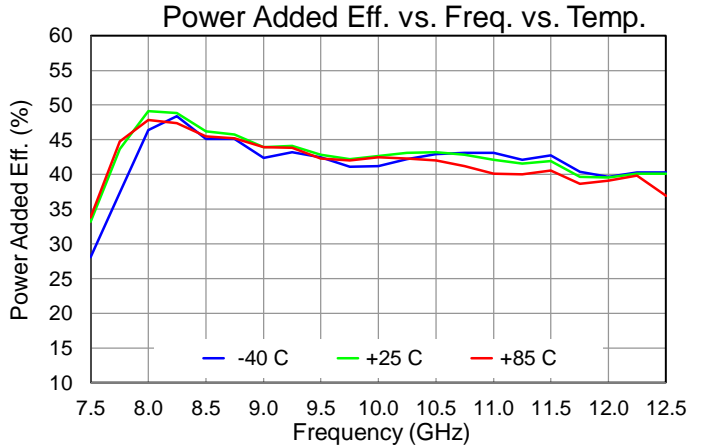
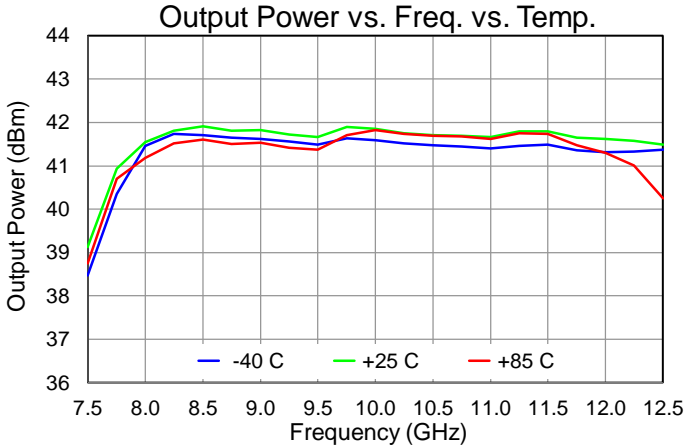
## Electrical Specifications

Parameter	Conditions	Min	Typ	Max	Units
Operational Frequency		8		12	GHz
Output Power ( $P_{IN} = 18$ dBm)	Pulsed $V_D$		41.7		dBm
Power Added Efficiency ( $P_{IN} = 18$ dBm)	Pulsed $V_D$		43.5		%
Small Signal Gain (CW)			34.2		dB
Input Return Loss (CW)			21		dB
Output Return Loss (CW)			6		dB
3 <sup>RD</sup> Order IMD ( $P_{IN}/Tone = 5$ dBm)	10 MHz tone spacing		-14		dBc
$P_{OUT}$ Temp. Coeff. (85 °C to 25 °C, $P_{IN} = 18$ dBm)			-0.003		dB/°C
Sm. Sig. Gain Temp. Coefficient (85 °C to -40 °C)			-0.105		dB/°C
Gate Leakage Current	$V_D = 10$ V, $V_G = -3.7$ V	-5.37			mA

Test conditions, unless otherwise noted: T = +25 °C,  $V_D = 24$  V,  $I_{DQ} = 250$  mA, Pulse Width = 100 us, Duty Cycle = 10%

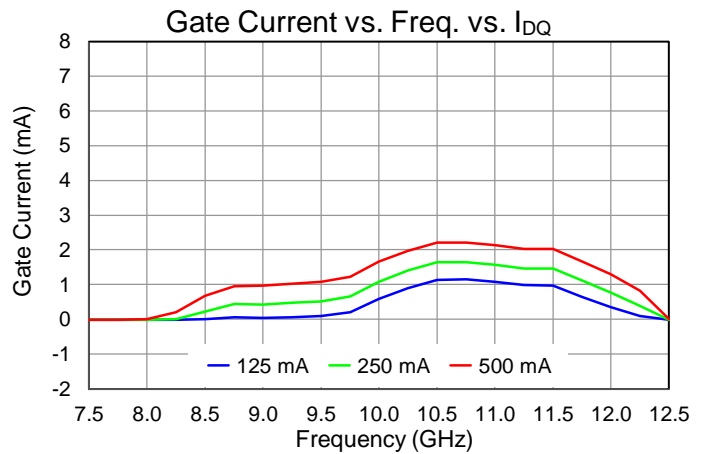
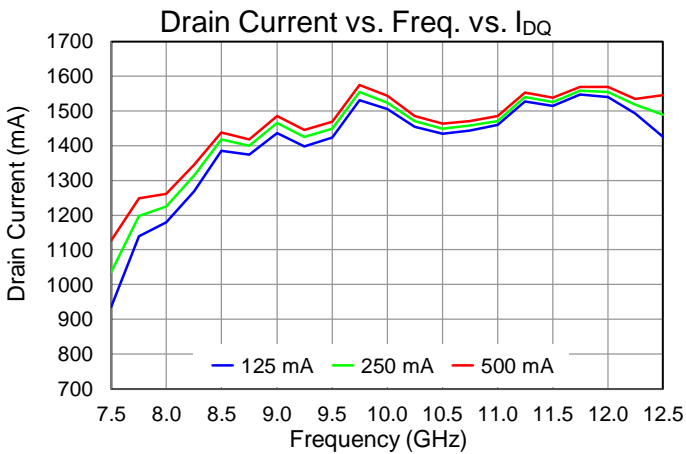
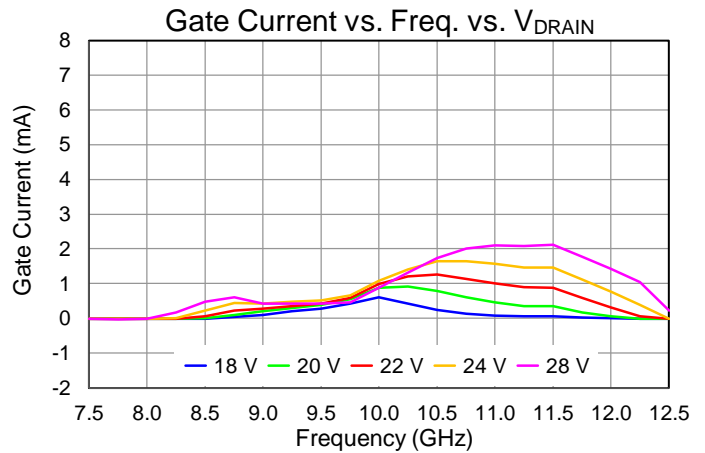
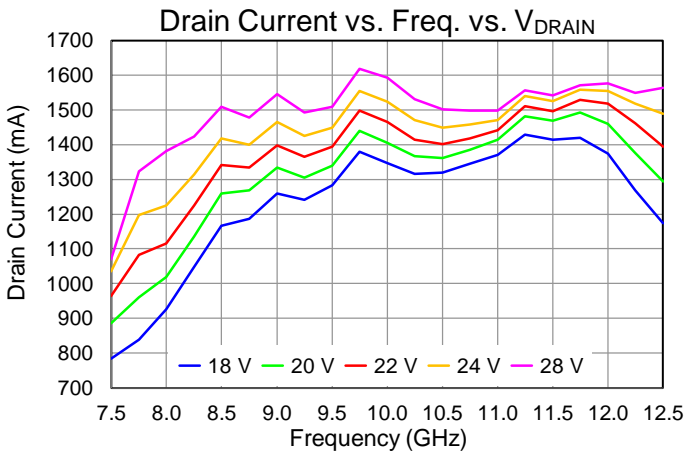
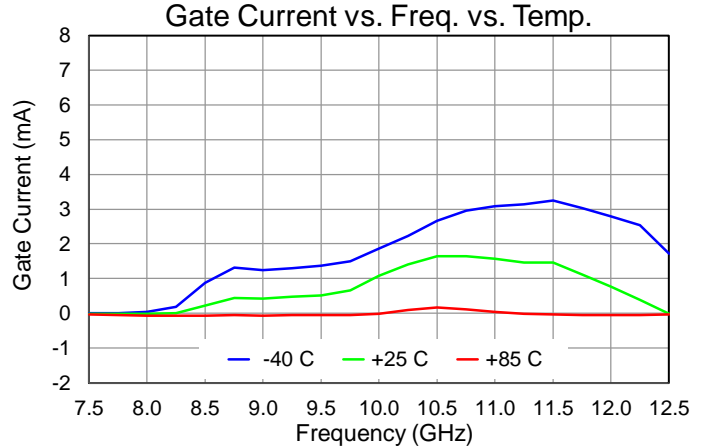
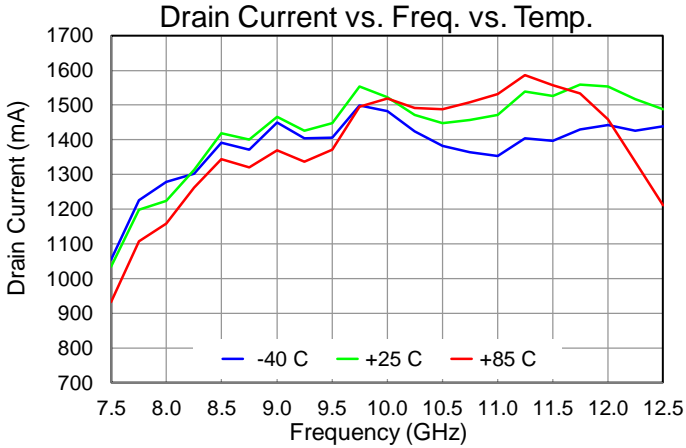
## Performance Plots – Large Signal (Pulsed)

Test conditions unless otherwise noted:  $T = +25\text{ }^{\circ}\text{C}$ ,  $V_D = 24\text{ V}$ ,  $I_{DQ} = 250\text{ mA}$ ,  $P_{IN} = 18\text{ dBm}$ , Pulse Width = 100  $\mu\text{s}$ , Duty Cycle = 10%



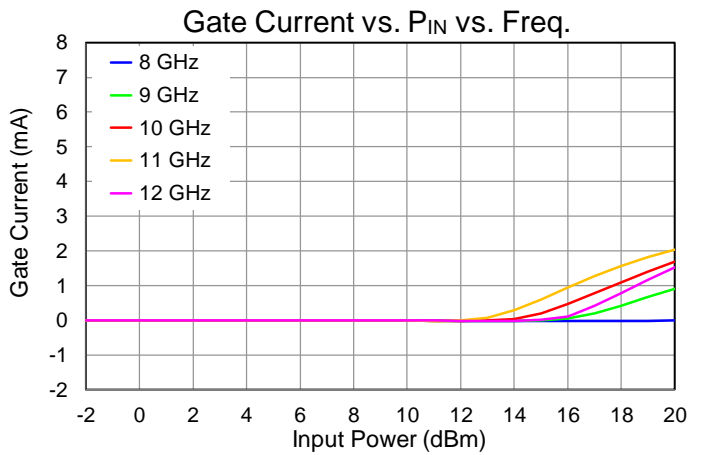
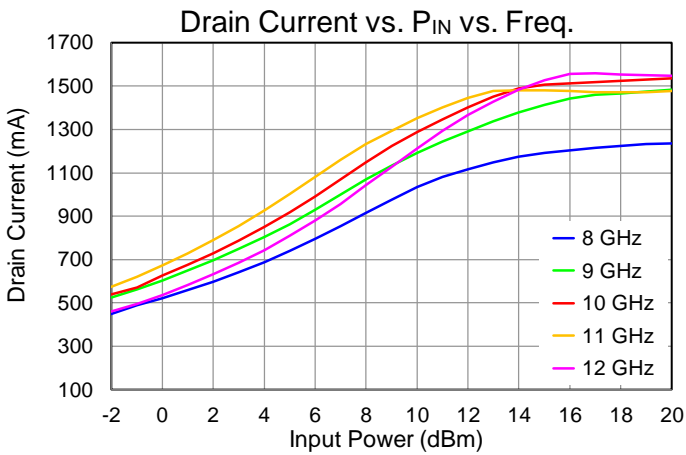
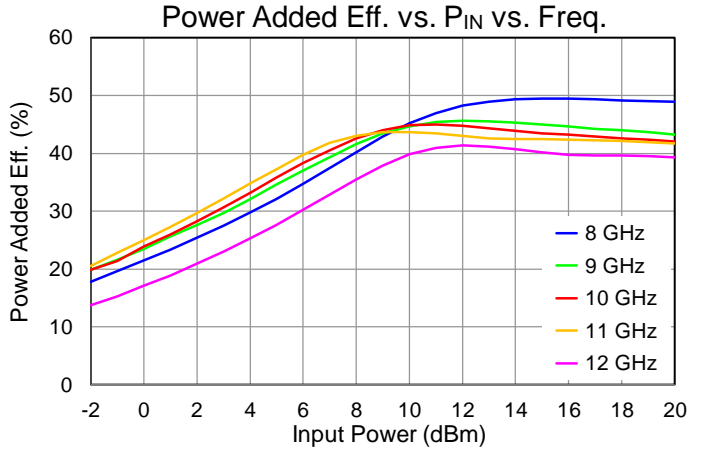
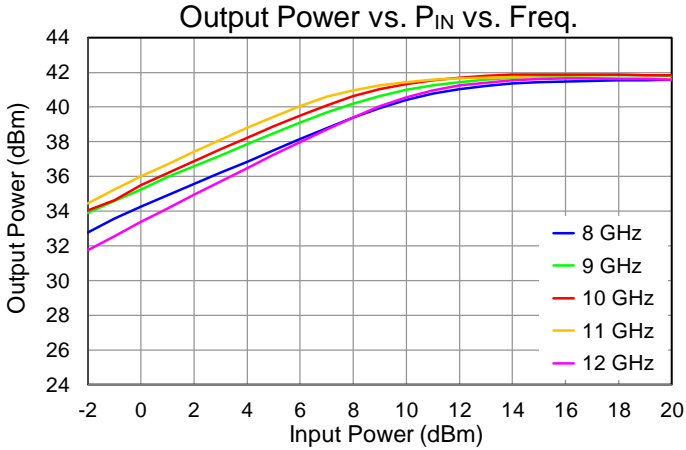
## Performance Plots – Large Signal (Pulsed)

Test conditions unless otherwise noted:  $T = +25\text{ }^{\circ}\text{C}$ ,  $V_D = 24\text{ V}$ ,  $I_{DQ} = 250\text{ mA}$ ,  $P_{IN} = 18\text{ dBm}$ , Pulse Width = 100  $\mu\text{s}$ , Duty Cycle = 10%



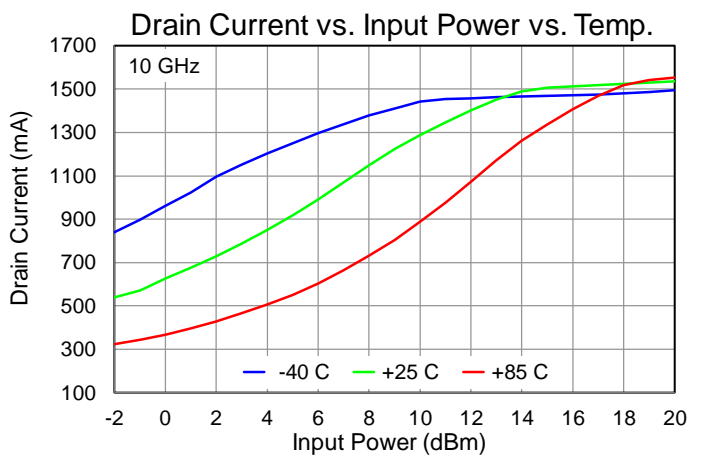
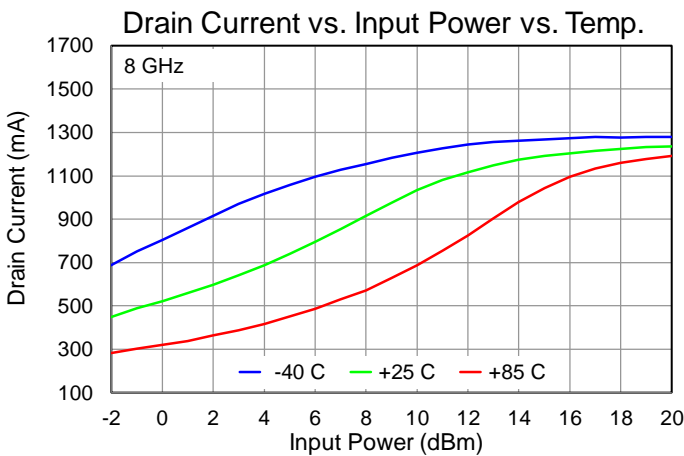
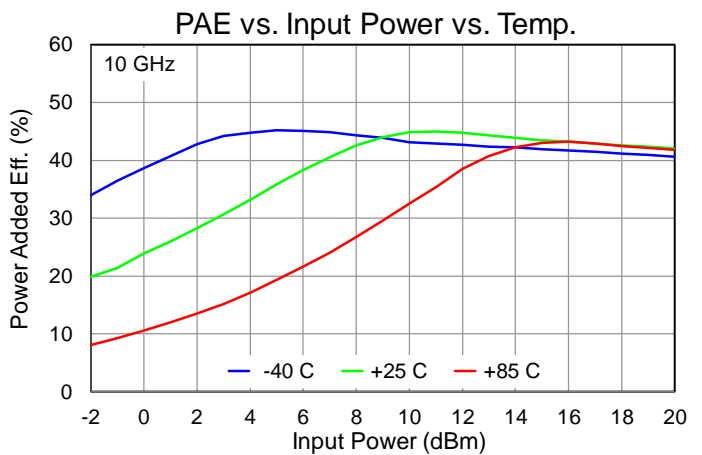
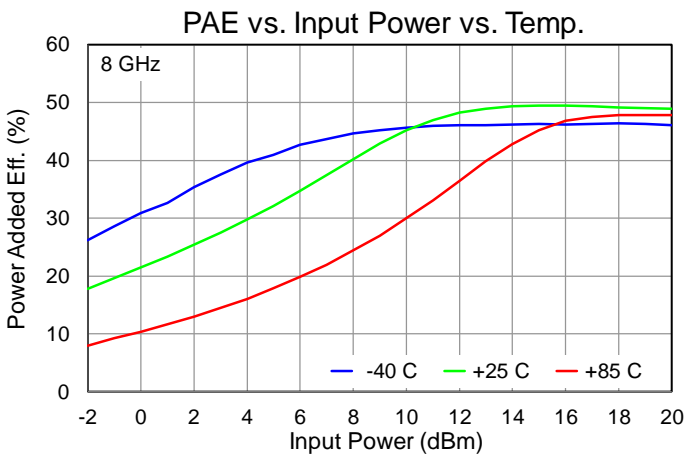
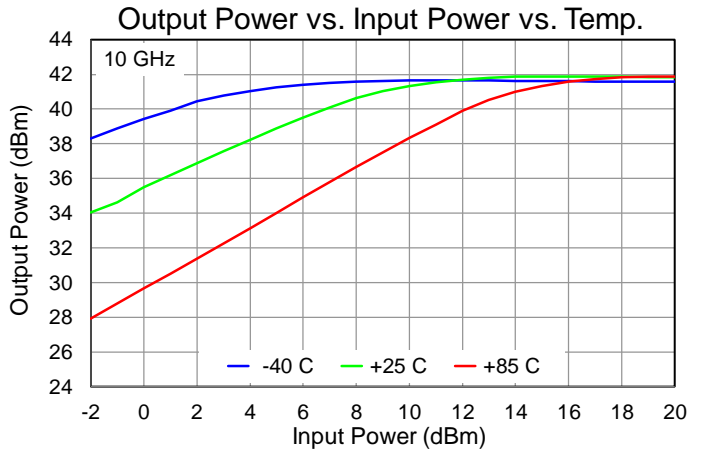
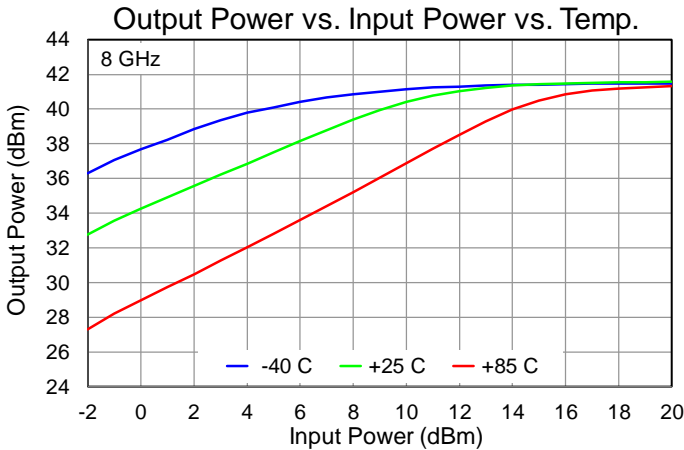
## Performance Plots – Large Signal (Pulsed)

Test conditions unless otherwise noted:  $T = +25\text{ }^{\circ}\text{C}$ ,  $V_D = 24\text{ V}$ ,  $I_{DQ} = 250\text{ mA}$ , Pulse Width = 100 us, Duty Cycle = 10%



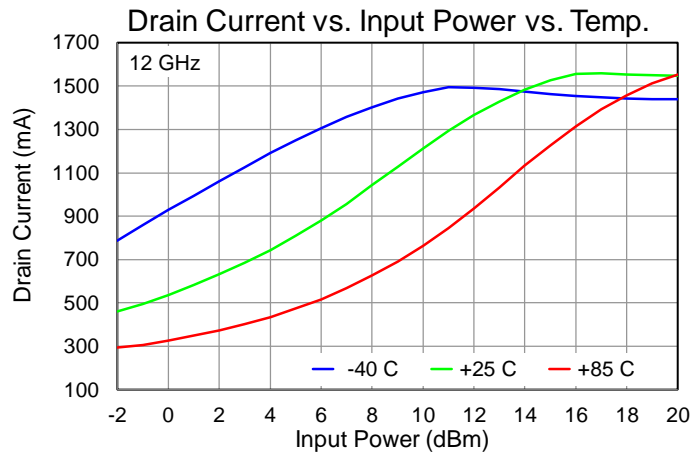
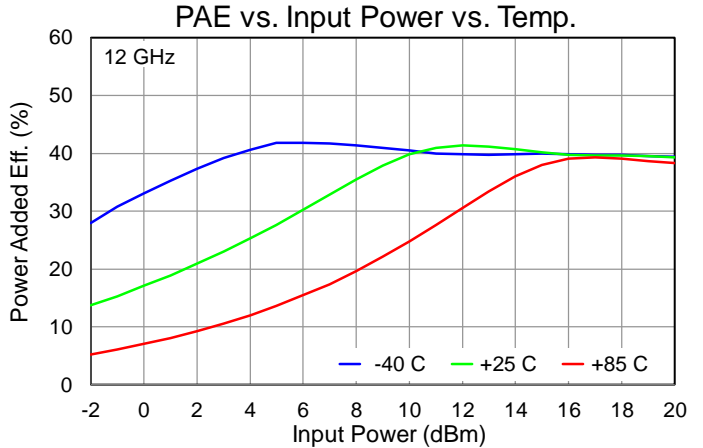
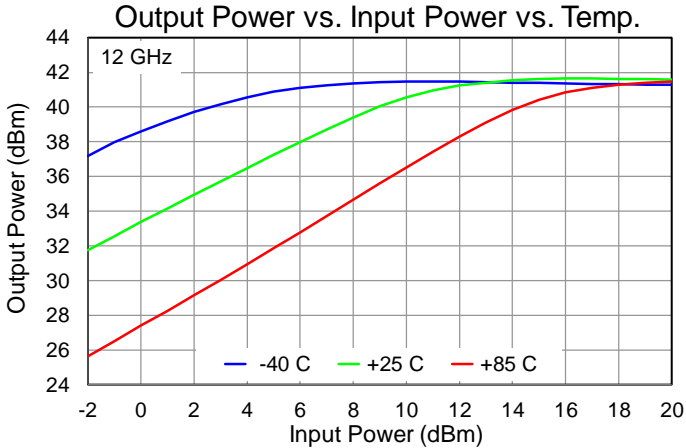
Performance Plots – Large Signal (Pulsed)

Test conditions unless otherwise noted: T = +25 °C, V<sub>D</sub> = 24 V, I<sub>DQ</sub> = 250 mA, Pulse Width = 100 us, Duty Cycle = 10%



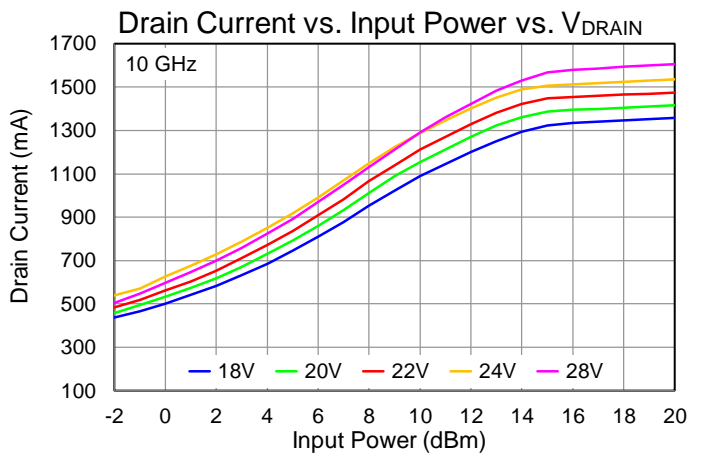
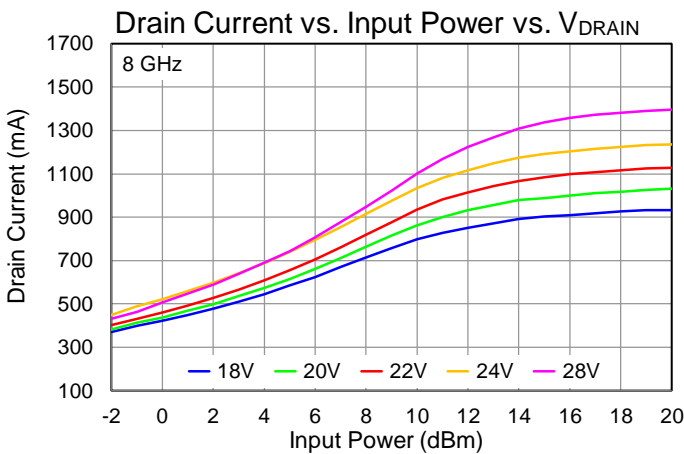
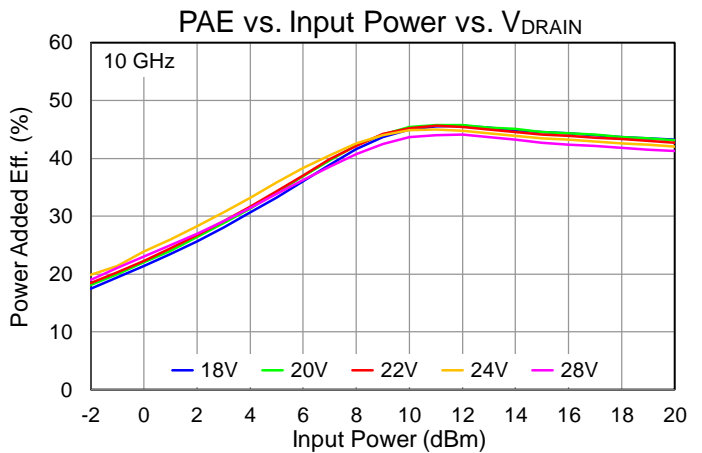
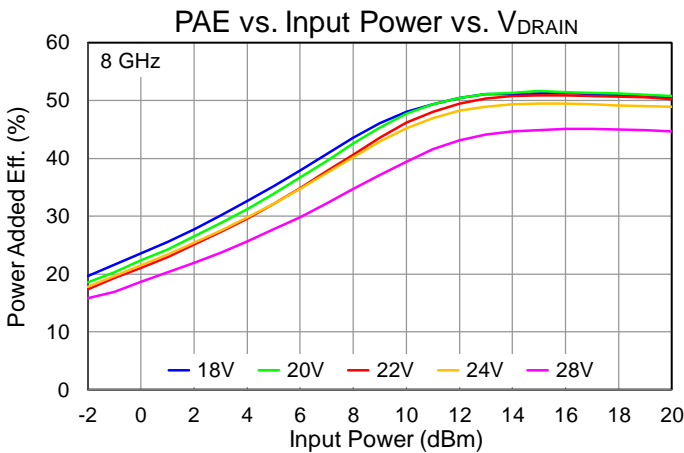
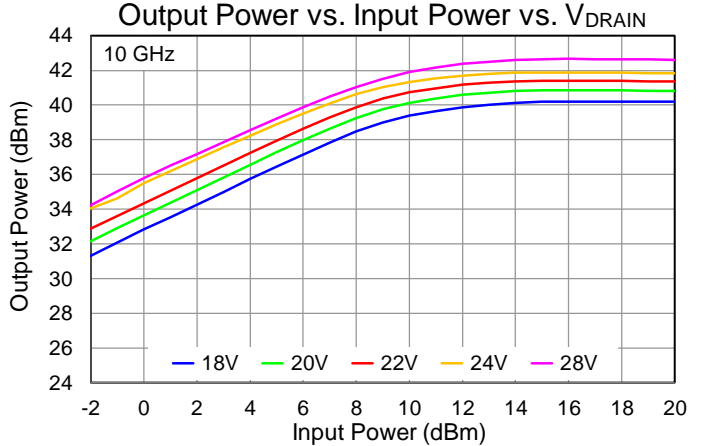
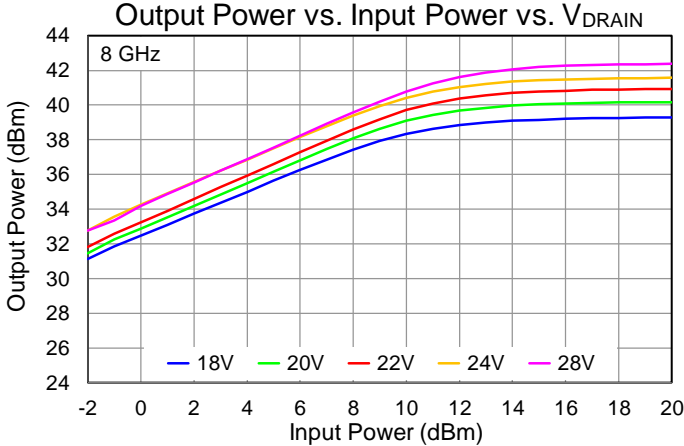
Performance Plots – Large Signal (Pulsed)

Test conditions unless otherwise noted: T = +25 °C, V<sub>D</sub> = 24 V, I<sub>DQ</sub> = 250 mA, Pulse Width = 100 us, Duty Cycle = 10%



Performance Plots – Large Signal (Pulsed)

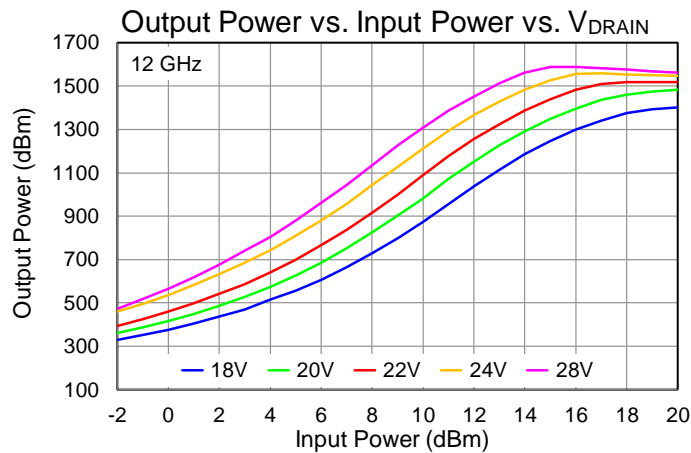
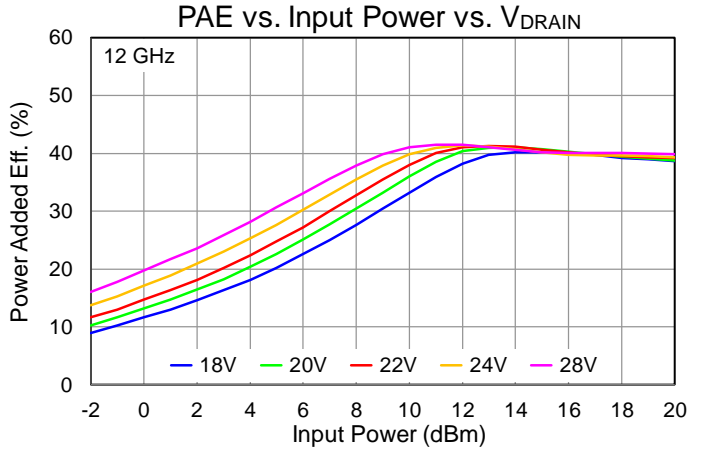
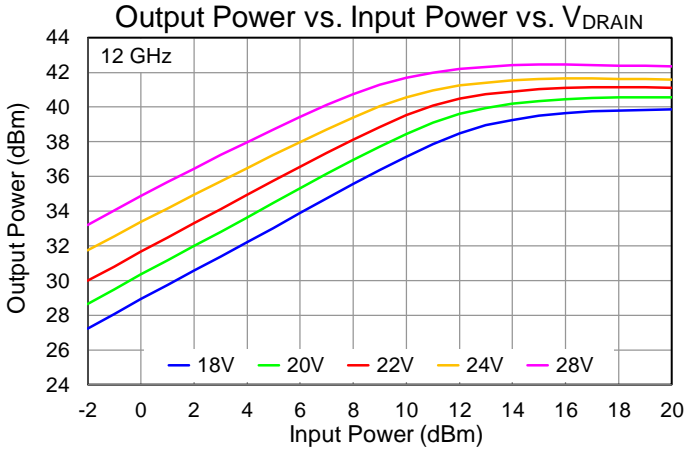
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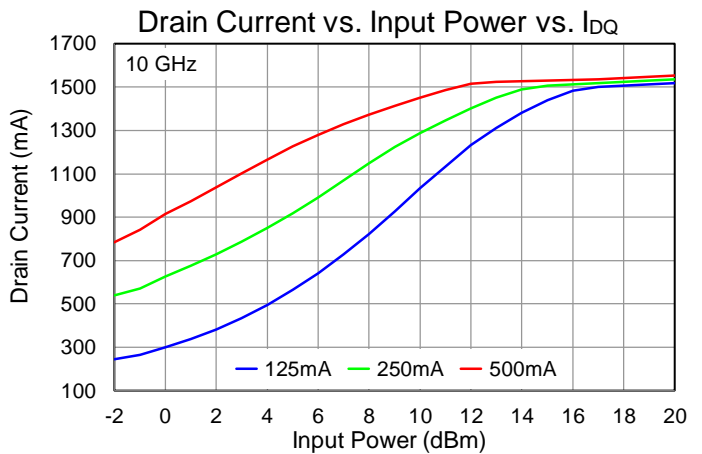
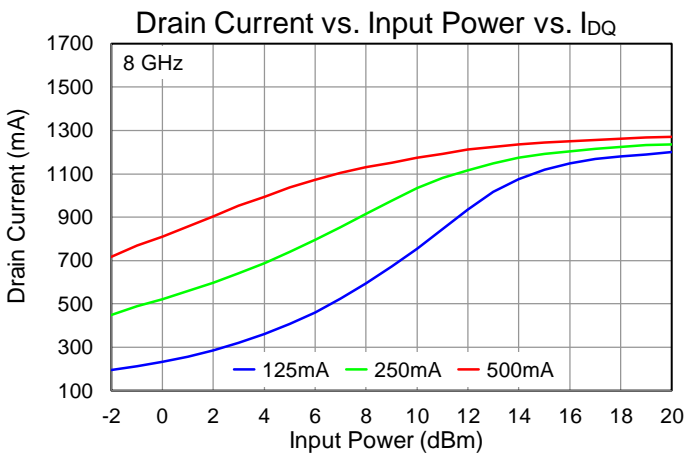
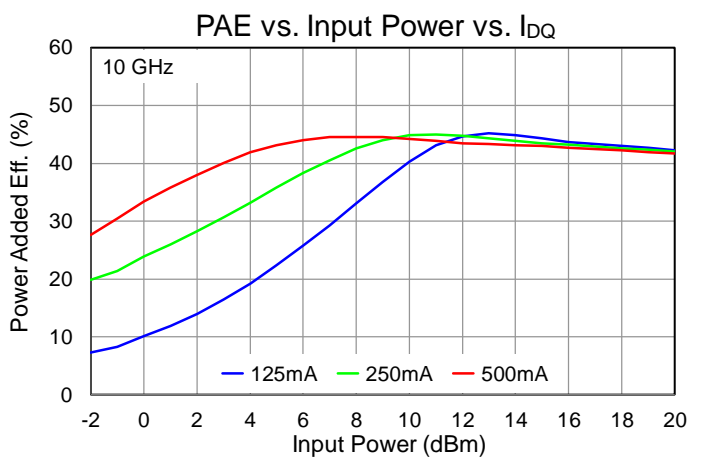
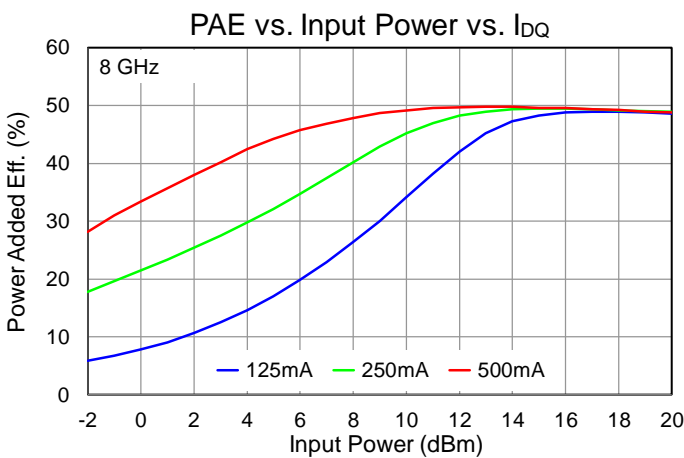
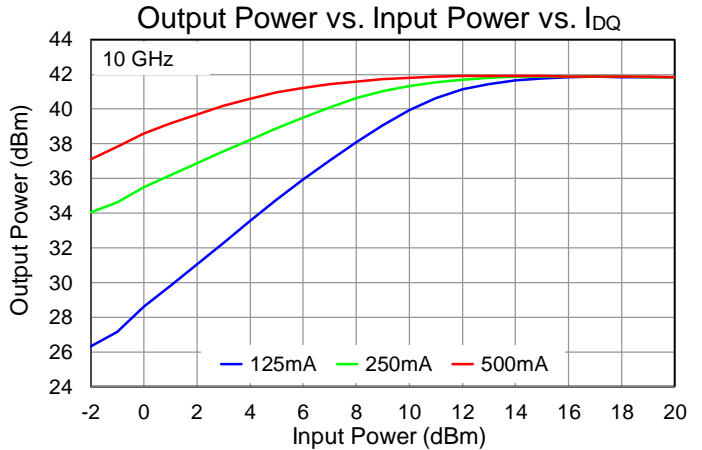
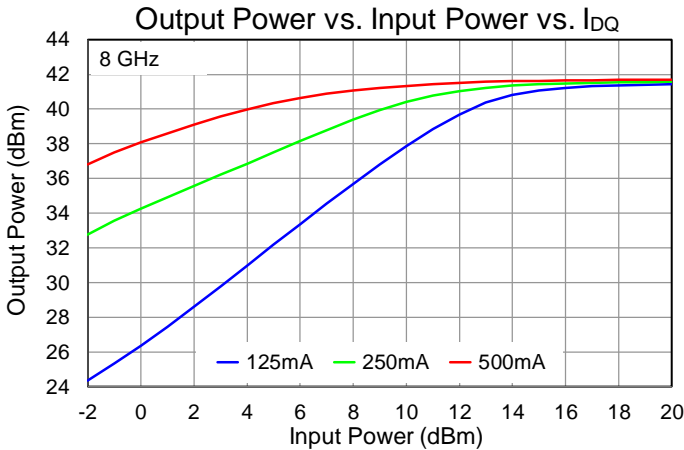
Performance Plots – Large Signal (Pulsed)

Test conditions unless otherwise noted: T = +25 °C, V<sub>D</sub> = 24 V, I<sub>DQ</sub> = 250 mA, Pulse Width = 100 us, Duty Cycle = 10%



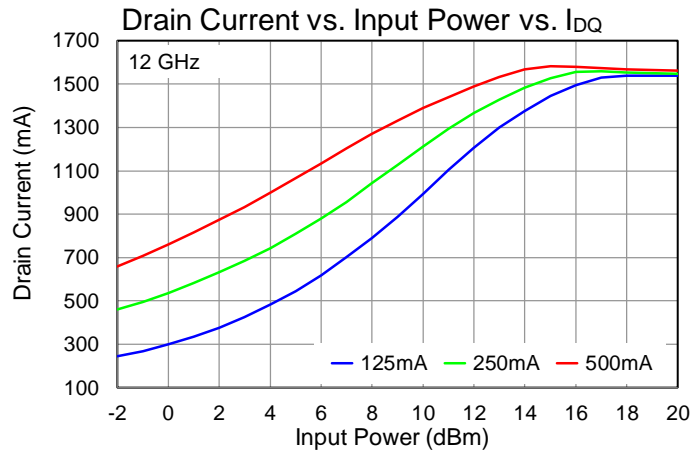
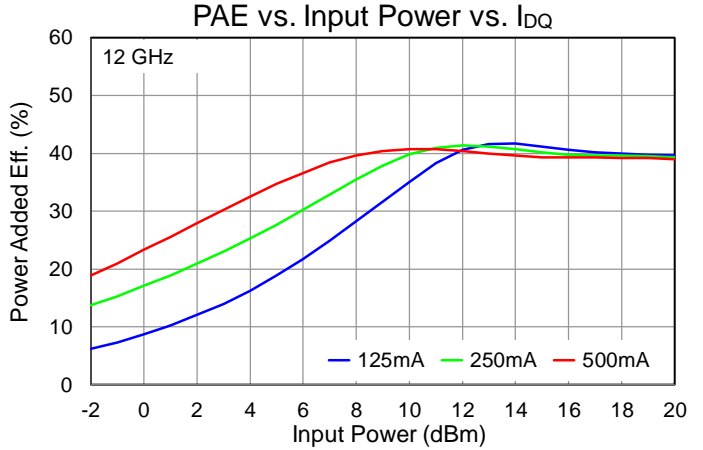
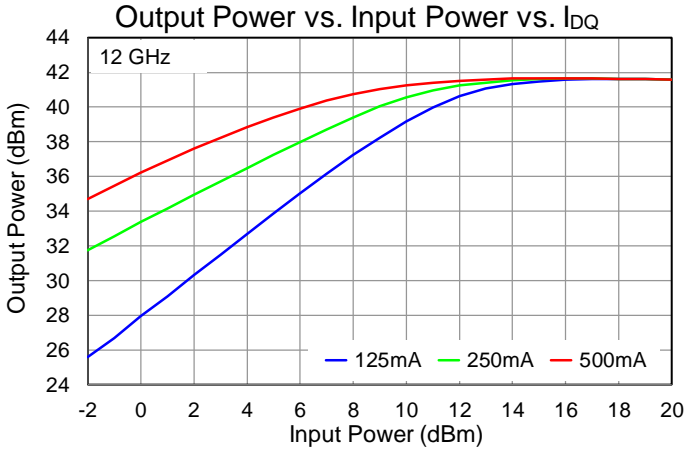
## Performance Plots – Large Signal (Pulsed)

Test conditions unless otherwise noted:  $T = +25\text{ }^{\circ}\text{C}$ ,  $V_D = 24\text{ V}$ ,  $I_{DQ} = 250\text{ mA}$ , Pulse Width = 100 us, Duty Cycle = 10%



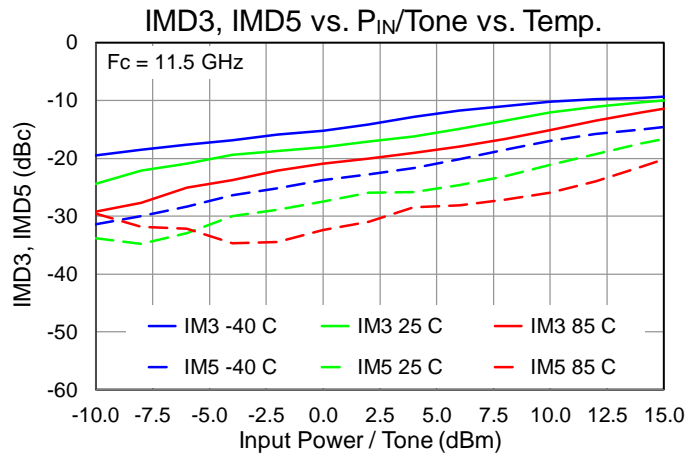
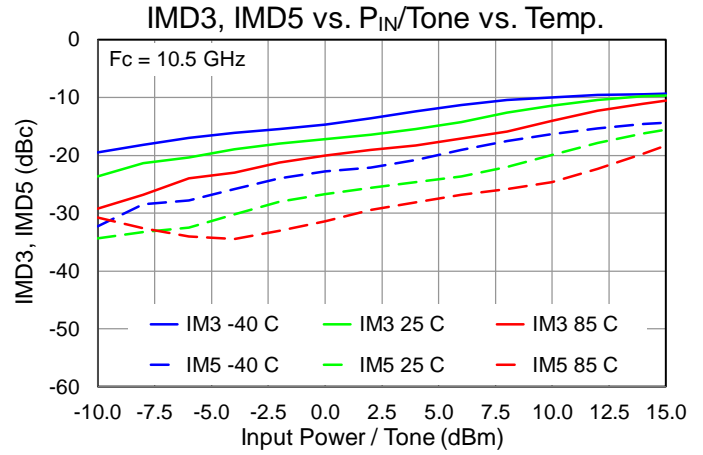
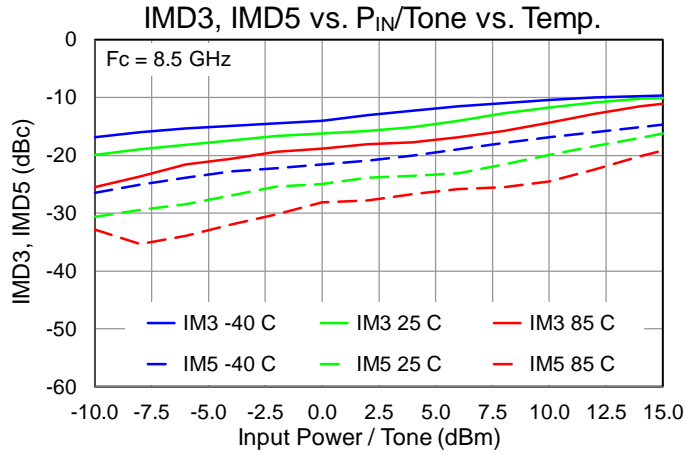
Performance Plots – Large Signal (Pulsed)

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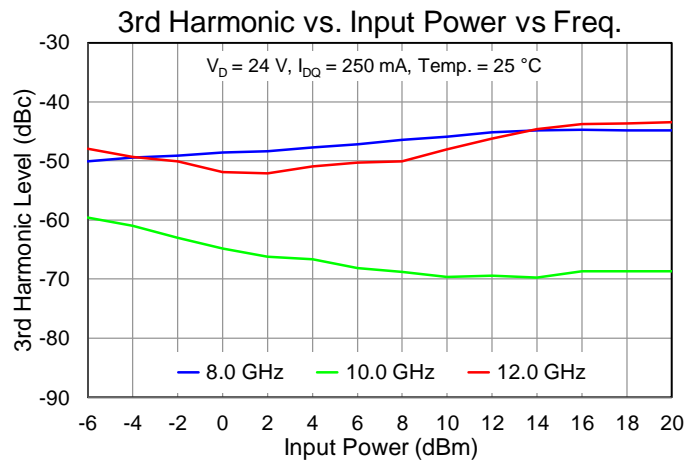
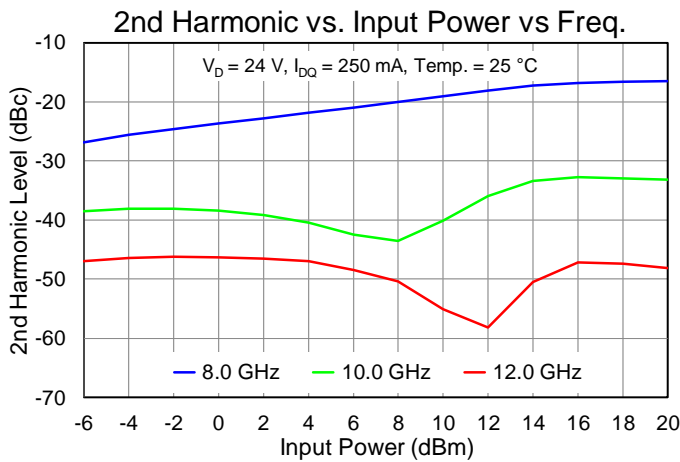
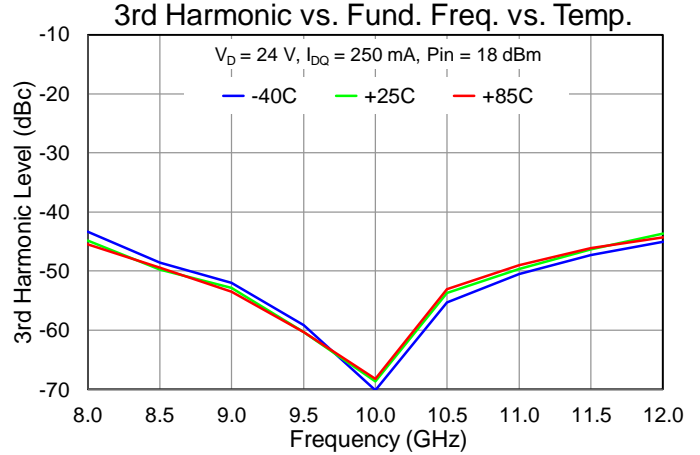
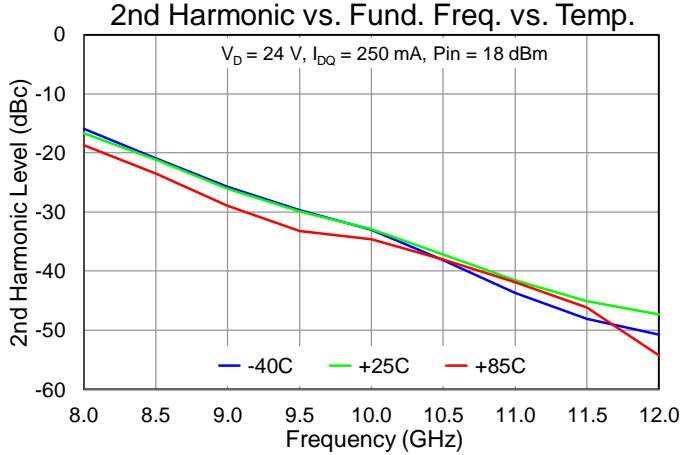
Performance Plots – Linearity

Test conditions unless otherwise noted:  $V_D = 24\text{ V}$ ,  $I_{BQ} = 250\text{ mA}$ ,  $T = 25\text{ }^\circ\text{C}$ , 10 MHz Tone Spacing, CW



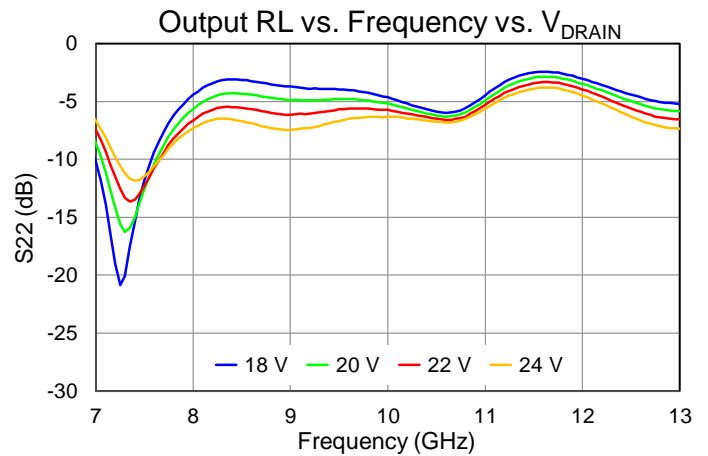
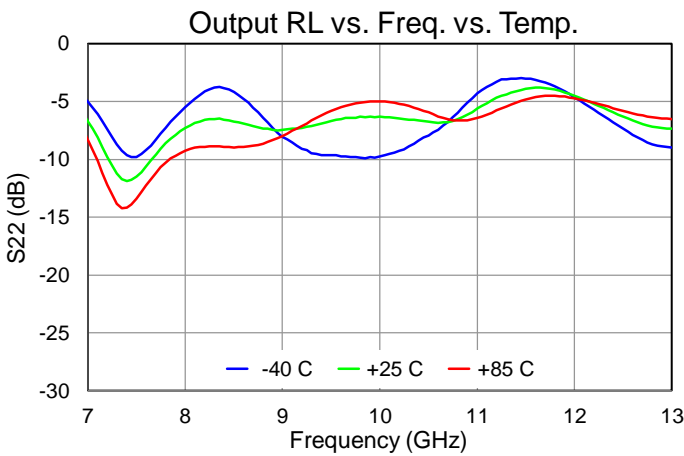
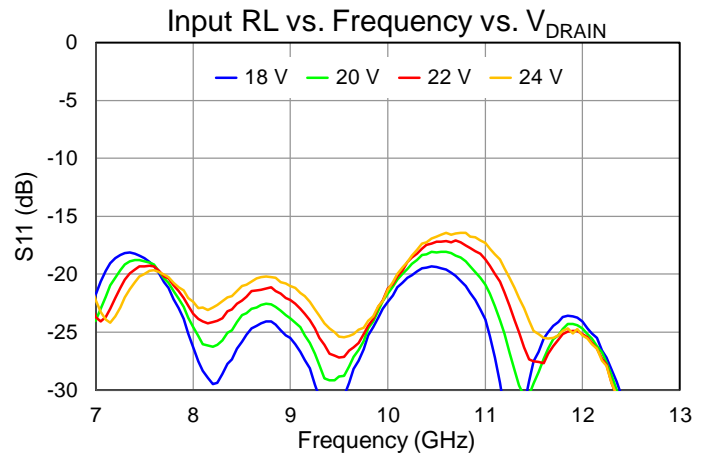
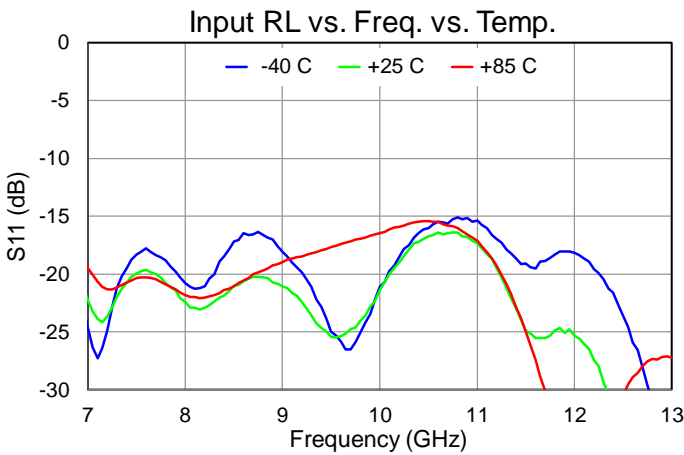
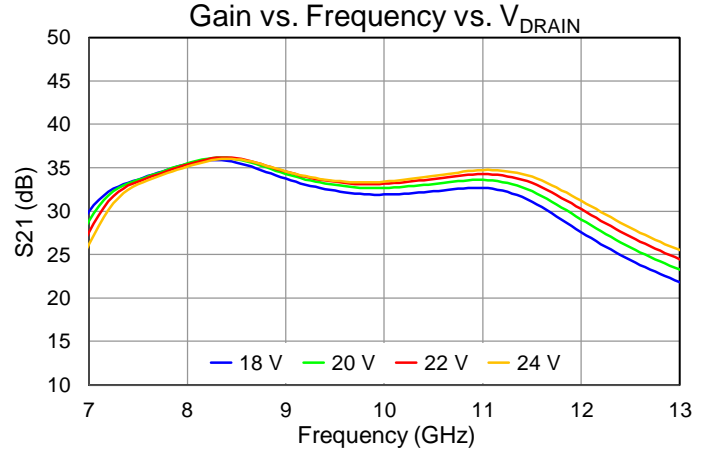
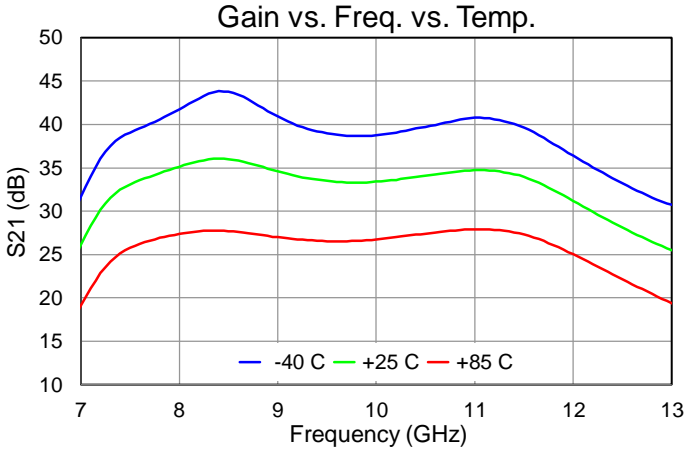
Performance Plots – Harmonics

Test conditions unless otherwise noted: T = +25 °C, V<sub>D</sub> = 24 V, I<sub>DQ</sub> = 250 mA, Pulse Width = 100 us, Duty Cycle = 10%



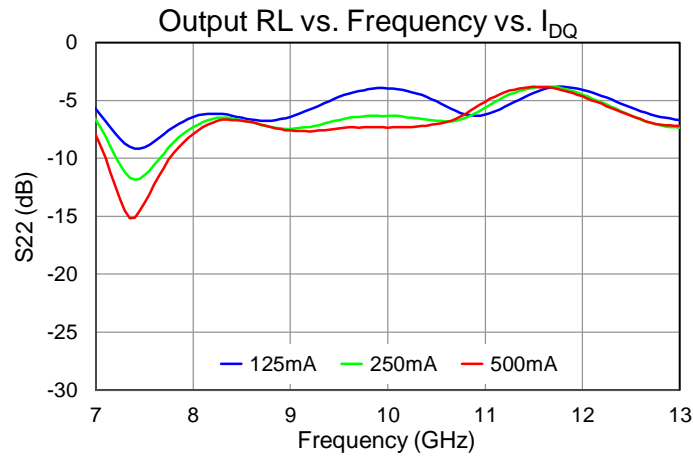
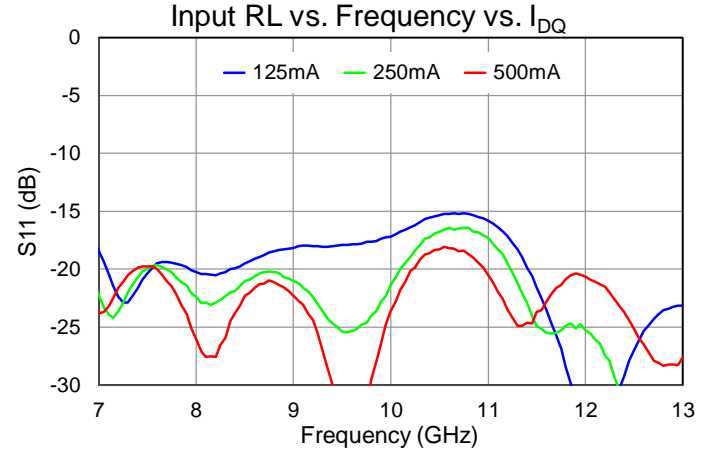
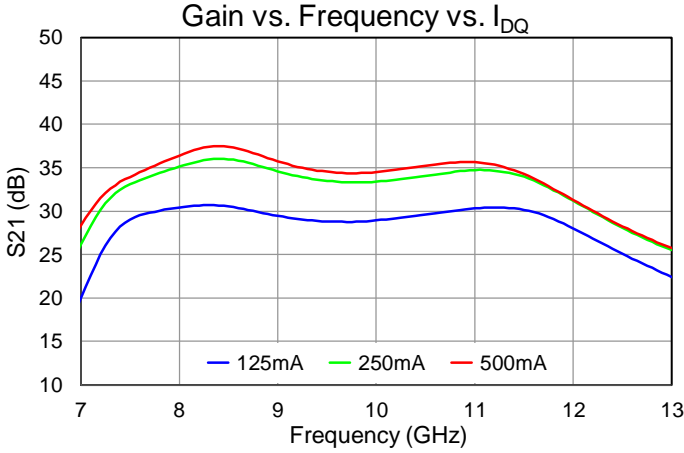
Performance Plots – Small Signal

Test conditions unless otherwise noted: T = +25 °C, V<sub>D</sub> = 24 V, I<sub>DQ</sub> = 250 mA, CW



Performance Plots – Small Signal

Test conditions unless otherwise noted: T = +25 °C, V<sub>D</sub> = 24 V, I<sub>DQ</sub> = 250 mA, CW



## Thermal and Reliability Information

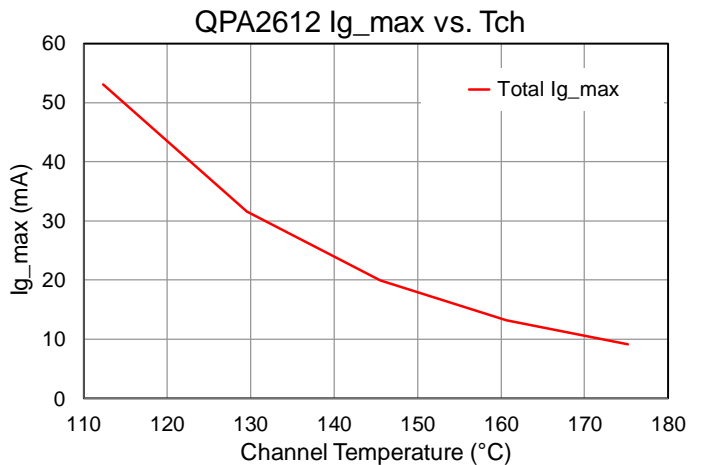
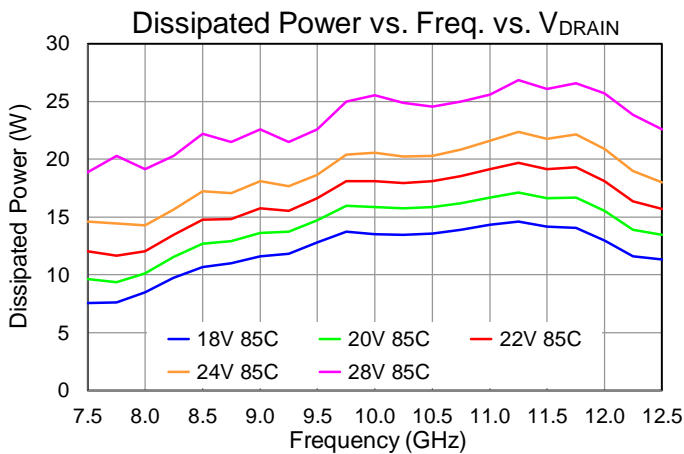
Parameter	Test Conditions	Value	Units
Thermal Resistance ( $\theta_{JC}$ ) <sup>(1)</sup>	$T_{base} = +85\text{ }^{\circ}\text{C}$ , $V_D = 24\text{ V}$ , $I_{DQ} = 250\text{ mA}$ , $P_{DISS} = 6.0\text{ W}$ (CW, quiescent, no RF)	3.563	$^{\circ}\text{C/W}$
Channel Temperature, $T_{CH}$ (Under RF) <sup>(2)</sup>		106.4	$^{\circ}\text{C}$
Thermal Resistance ( $\theta_{JC}$ ) <sup>(1)</sup>	$T_{base} = +85\text{ }^{\circ}\text{C}$ , $V_D = 24\text{ V}$ , $I_{DQ} = 250\text{ mA}$ , $I_{D\_Drive} = 1586\text{ mA}$ , $P_{OUT} = 41.8\text{ dBm}$ , $P_{IN} = 18\text{ dBm}$ , Freq. = 11.25 GHz, $P_{DISS} = 22.4\text{ W}$ (Pulse: 100us/10%)	2.834	$^{\circ}\text{C/W}$
Channel Temperature, $T_{CH}$ (Under RF) <sup>(2)</sup>		148.5	$^{\circ}\text{C}$
Thermal Resistance ( $\theta_{JC}$ ) <sup>(1)</sup>	$T_{base} = +85\text{ }^{\circ}\text{C}$ , $V_D = 28\text{ V}$ , $I_{DQ} = 250\text{ mA}$ , $I_{D\_Drive} = 1663\text{ mA}$ , $P_{OUT} = 42.8\text{ dBm}$ , $P_{IN} = 18\text{ dBm}$ , Freq. = 11.25 GHz, $P_{DISS} = 26.8\text{ W}$ (Pulse: 100us/10%)	2.794	$^{\circ}\text{C/W}$
Channel Temperature, $T_{CH}$ (Under RF) <sup>(2)</sup>		159.9	$^{\circ}\text{C}$

**Notes:**

1. Thermal resistance is referenced to the back of the package.
2. IR scan equivalent temperatures. Refer to the following document: [GaN Device Channel Temperature, Thermal Resistance, and Reliability Estimates](#)

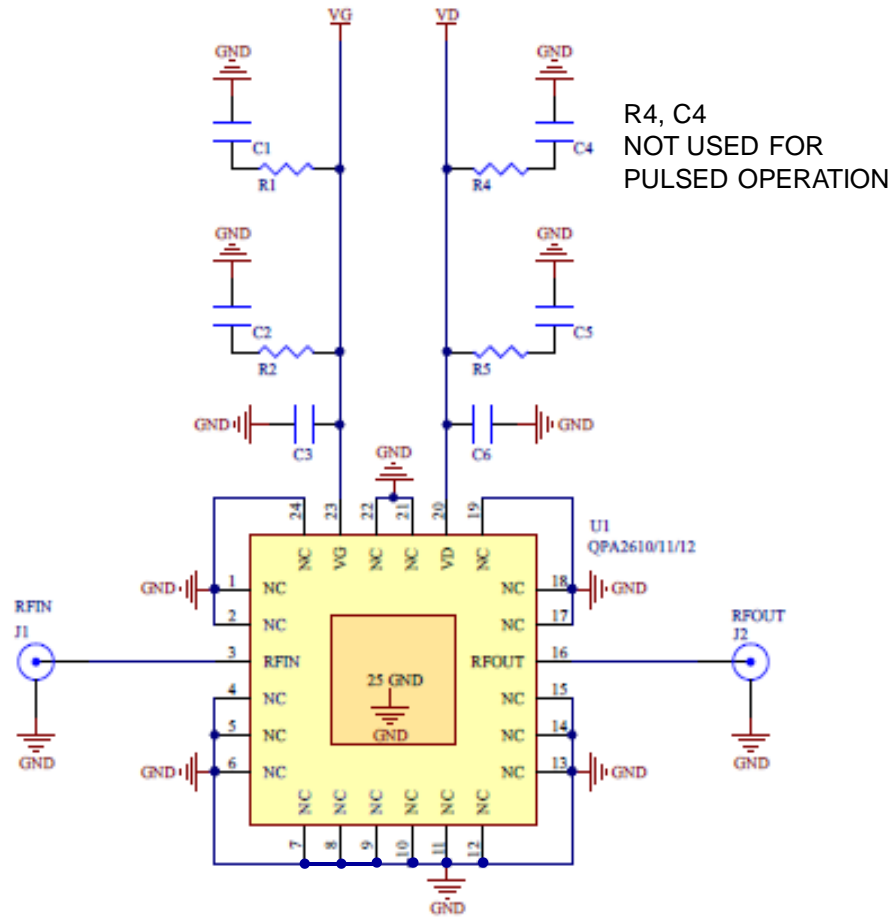
## Power Dissipation and Maximum Gate Current

$P_{IN} = 18\text{ dBm}$ , Pulse Width = 100 us, Duty Cycle = 10%





Application Information



**Bias-up Procedure**

Set  $I_D$  limit to 1800 mA,  $I_G$  limit to 10 mA

Apply -4 V to  $V_G$

Apply +24 V to  $V_D$ ; ensure  $I_{DQ}$  is approx. 0 mA

Adjust  $V_G$  until  $I_{DQ} = 250$  mA

Turn on RF supply

**Bias-down Procedure**

Turn off RF signal

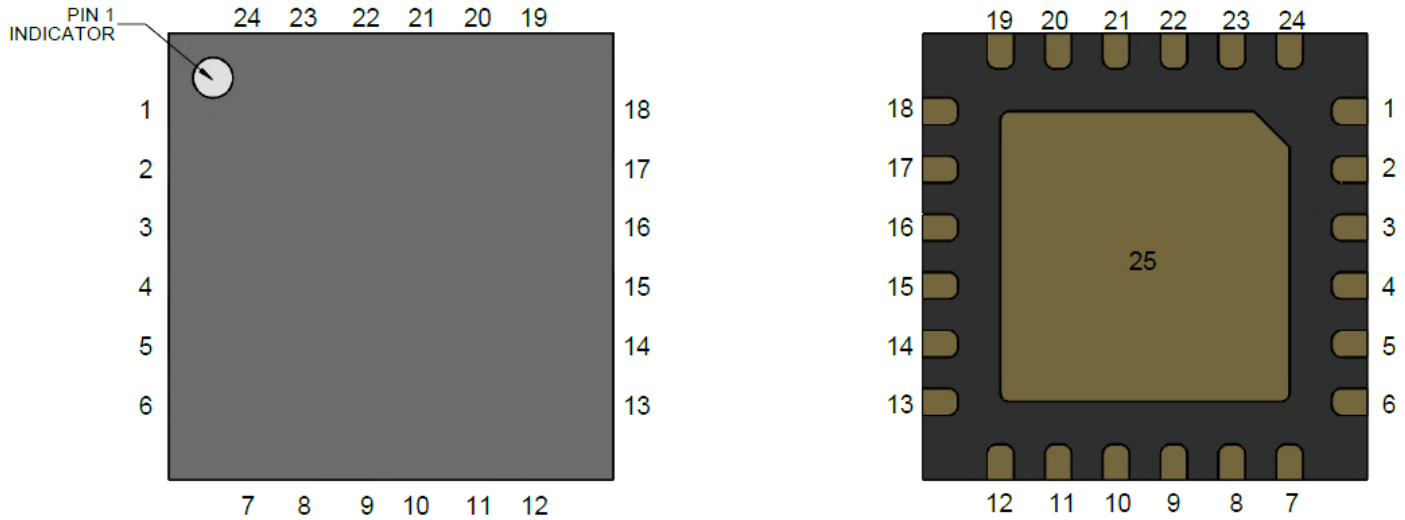
Reduce  $V_G$  to -4 V; ensure  $I_{DQ}$  is approx. 0 mA

Set  $V_D$  to 0 V

Turn off  $V_D$  supply

Turn off  $V_G$  supply

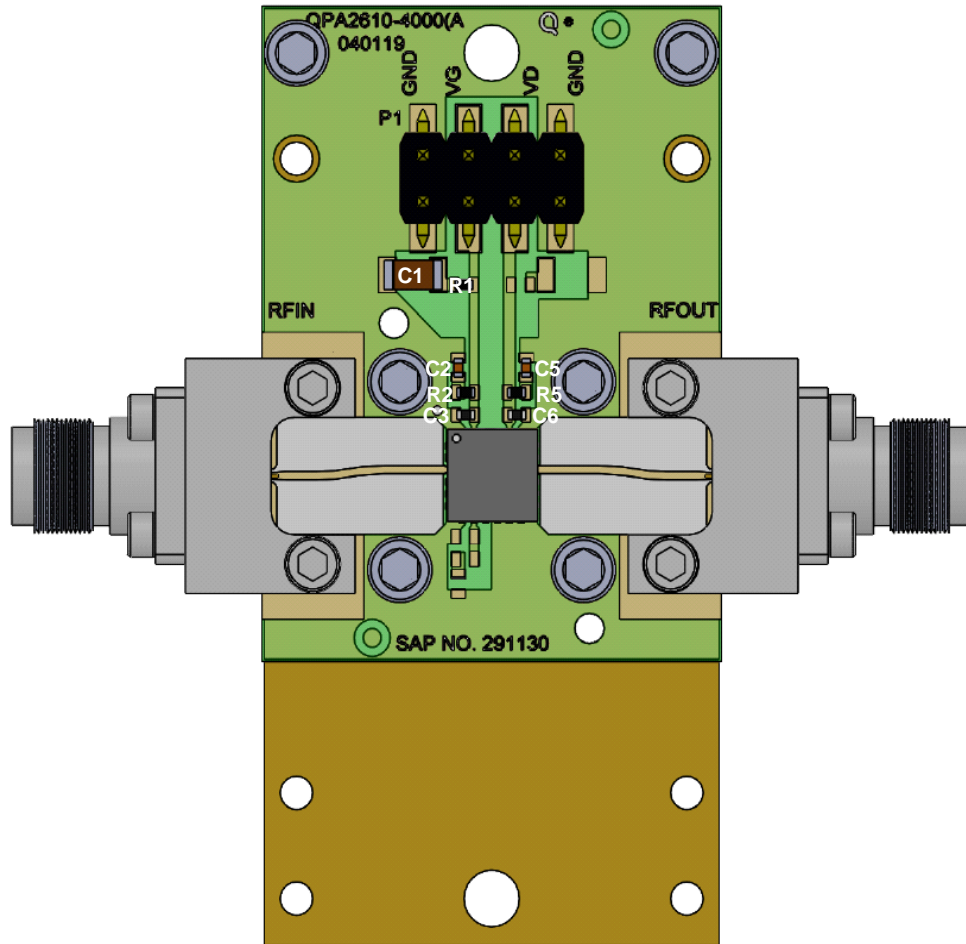
## Pin Layout



## Pin Description

Pin Number	Symbol	Description
1, 2, 4-15, 17-19, 21, 22, 24	NC	No connection inside of package. Connection to PCB ground recommended
3	RF IN	RF input. 50 $\Omega$ , DC blocked, pad connected to ground
16	RF OUT	RF output. 50 $\Omega$ , DC blocked, pad connected to ground
20	VD	Drain voltage. Bypass network required; refer to page 19
23	VG	Gate voltage. Bypass network required; refer to page 19
25	GND	Center paddle ground

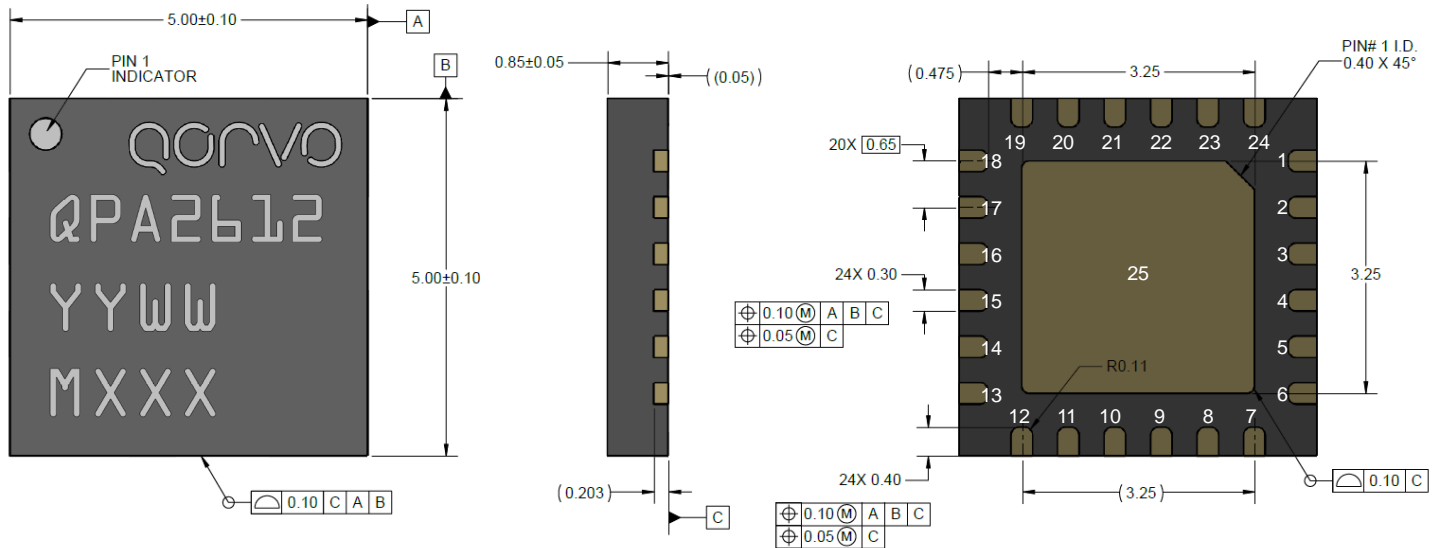
Evaluation Board



Bill of Materials

Ref. Des.	Value	Description	Manuf.	Part Number
C1	10 uF	CAP, 10uF, 20%, 50V, 20%, X5R, 1206	various	
C3,C6	1000 pF	CAP, 1000pF, 10%, 100V, X7R, 0402	various	
C2,C5	0.1 uF	CAP, 0.1uF, 10%, 50V, X7R, 0402	various	
R2,R5	10 Ω	RES, 10 OHM, 5%, 0.1W, 0402	various	
R1	0 Ω	RES, 0 OHM, JMPR, 0402	various	
J1, J2		2.92mm Female End Launch Connector	Southwest Microwave	1092-01A-5

**Mechanical Information**



**NOTES:**

Package base and leads are Ni-Au plated

Part Markings:

Part Number: QPA2612

Part Assembly Year: YY

Part Assembly Week: WW

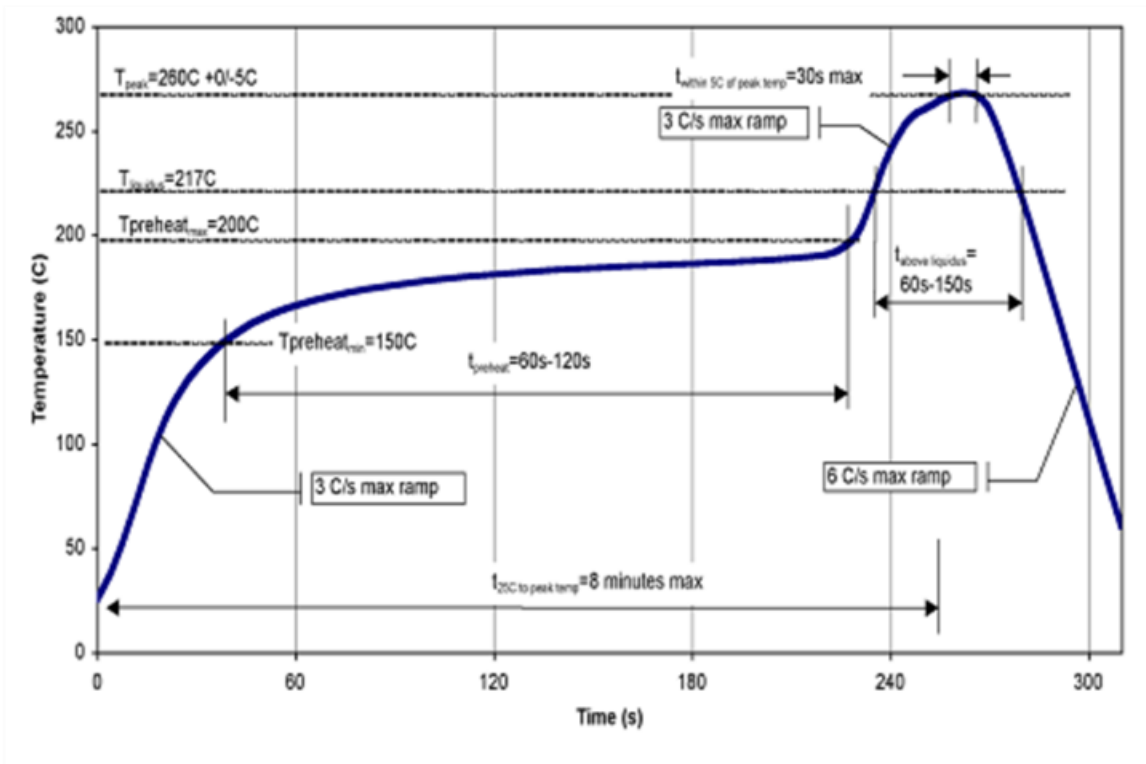
Lot Number: MXXX

Dimensions are in millimeters

Assembly Notes

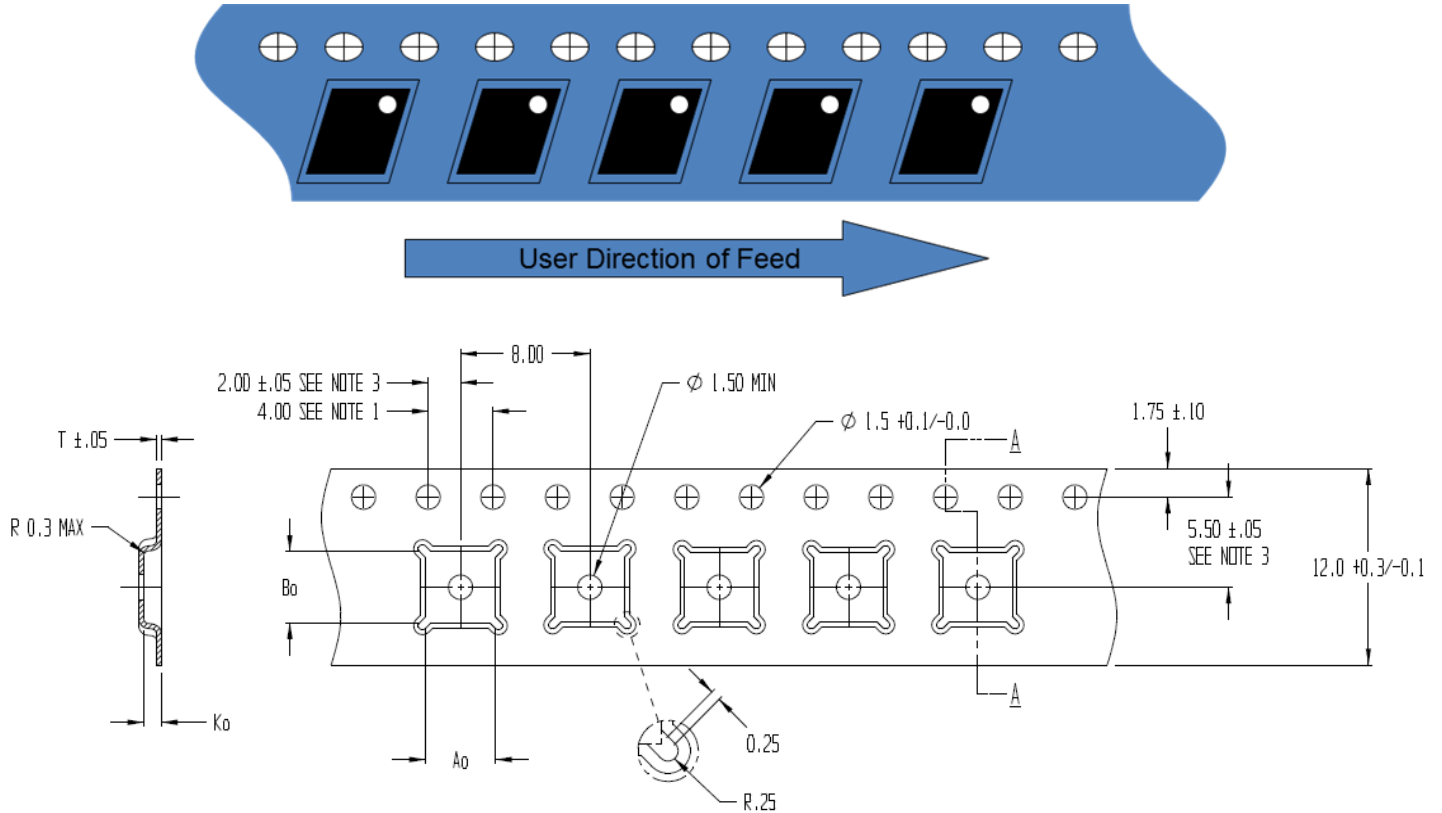
Compatible with lead-free soldering processes with 260°C peak reflow temperature.

Contact plating: Ni-Au.



Recommended Soldering Temperature Profile

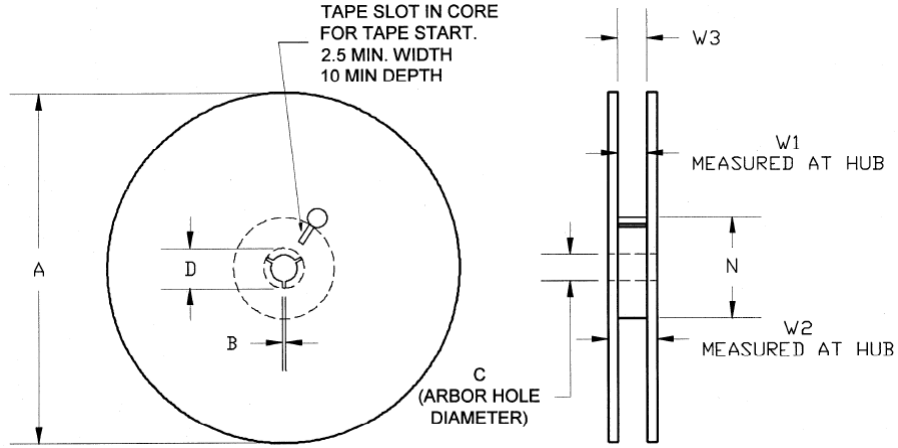
**Tape and Reel Information – Carrier and Cover Tape Dimensions**



Feature	Measure	Symbol	Size (in)	Size (mm)
Cavity	Length	A0	0.189	4.80
	Width	B0	0.209	5.30
	Depth	K0	0.051	1.30
	Pitch	P1	0.315	8.00
Centerline Distance	Cavity to Perforation - Length Direction	P2	0.079	2.00
	Cavity to Perforation - Width Direction	F	0.217	5.50
Cover Tape	Width	C	0.362	9.20
Carrier Tape	Width	W	0.472	12.00

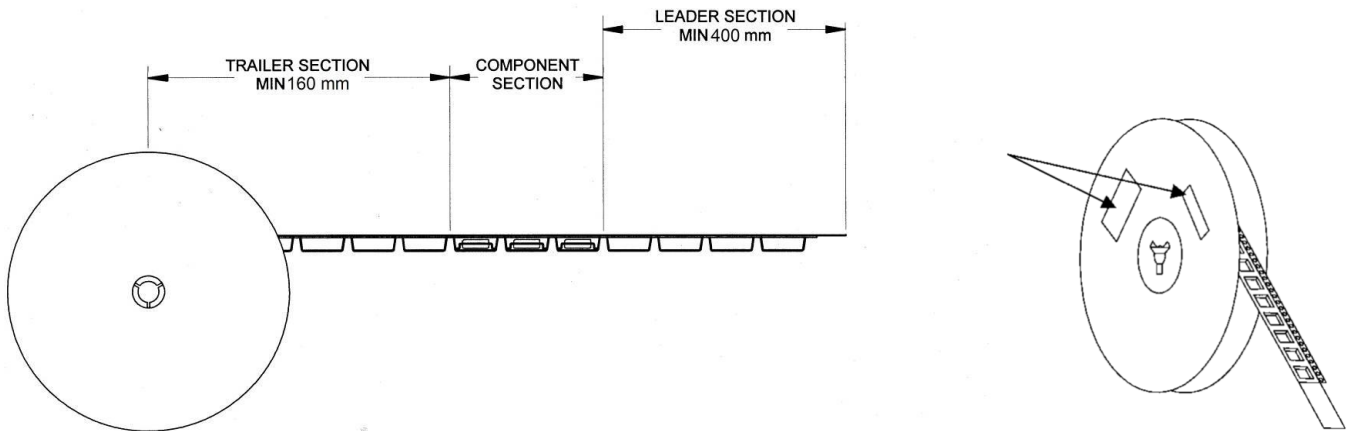
**Tape and Reel Information – Reel Dimensions**

Standard T/R size = 500 pieces on a 7" reel.



Feature	Measure	Symbol	Size (in)	Size (mm)
Flange	Diameter	A	6.969	177.0
	Thickness	W2	0.717	18.2
	Space Between Flange	W1	0.504	12.8
Hub	Outer Diameter	N	2.283	58.0
	Arbor Hole Diameter	C	0.512	13.0
	Key Slit Width	B	0.079	2.0
	Key Slit Diameter	D	0.787	20.0

**Tape and Reel Information – Tape Length and Label Placement**



- Notes:
1. Empty part cavities at the trailing and leading ends are sealed with cover tape. See EIA 481-1-A.
  2. Labels are placed on the flange opposite the sprockets in the carrier tape.

## Handling Precautions

Parameter	Rating	Standard
ESD – Human Body Model (HBM)	1B	ESDA / JEDEC JS-001-2014
ESD – Charged Device Model (CDM)	C3	ESDA / JEDEC JS-002-2017
MSL – Moisture Sensitivity Level	3	IPC/JEDEC J-STD-020



Caution!  
ESD-Sensitive Device

## RoHS Compliance

This part is compliant with 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment) as amended by Directive 2015/863/EU.

This product also has the following attributes:

- Lead Free
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A (C<sub>15</sub>H<sub>12</sub>Br<sub>4</sub>O<sub>2</sub>) Free
- SVHC Free

## Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations:

**Web:** [www.qorvo.com](http://www.qorvo.com)

**Tel:** 1-844-890-8163

**Email:** [customer.support@qorvo.com](mailto:customer.support@qorvo.com)

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